



Proceeding Paper Numerical Simulation of Lead-Free Sn-Based Perovskite Solar Cell by Using SCAPS-1D⁺

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Abstract: Recent developments based on lead (Pb) halide perovskites have inspired extensive research into low-cost solar cells in attempt to overcome the primary issues such as stability and toxicity that occur in this area. Solar cell simulation of lead-free perovskite (CH₃NH₃SnBr₃) as an absorber-based solar cell was performed using SCAPS-1D simulation tool in this work. An impact of absorber layer thickness and working temperature on photovoltaic characteristics of CH₃NH₃SnBr₃-based perovskite solar cells was investigated using numerical modeling techniques. The thickness was varied from 1.0 μ m to 3.0 μ m, and working temperature was varied from 290 K to 330 K, and their effect was examined on the photovoltaic parameters of proposed "Back Contact/CH₃NH₃SnBr₃/CdS/ZnO/Front Contact" solar cell. The improvement in the efficiency of solar cell by optimization of CH₃NH₃SnBr₃ absorber layer thickness and working temperature was working temperature was observed.

Keywords: perovskite; absorber layer; efficiency; simulation; SCAPS-1D

1. Introduction

Perovskite solar cells are becoming more important, because they have quickly increased in efficiency from 3.90% to 22.70% in recent years [1–5]. PCE has increased dramatically due to superior optoelectronic characteristics such as a high absorption coefficient (10^5 cm⁻¹), low exciton binding energy (20 meV), and a comparatively long carrier diffusion lifetime (>1 m). Furthermore, perovskite structural engineering from the basic methyl ammonium lead iodide (CH₃NH₃PbI₃) perovskite to novel mixed-cation and mixed-anion halide perovskite materials yields excellent efficiency [6–9]. Despite the tremendous progress, the total PCE of perovskite-based solar cells is still far from the Shockley–Queisser limit (SQL), which is 30.50 percent PCE for a single methyl ammonium lead iodide (MAPbI₃)-based junction cell. Again, it has been claimed that a NiO-based inverted structure device can outperform a planner structure in terms of stability [10].

Despite this, there are still a number of issues that prevent the manufacture of Snbased PVSC with bromine (Br) as the cation. This paper suggests a novel absorber layer using perovskite-CH₃NH₃SnBr₃ to build a non-toxic, highly efficient, and stable PVSC. We simulated a lead-free perovskite solar cell, using tin (Sn) instead of lead (Pb), as lead is a toxic material. We used SCAPS-1D simulator to validate the lead-free, Sn-based perovskite



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Copyright: © 2022 by the authors. Licensee MDPI, Basel, Switzerland. This article is an open access article distributed under the terms and conditions of the Creative Commons Attribution (CC BY) license (https:// creativecommons.org/licenses/by/ 4.0/). solar cell under dark and illuminated conditions. After that, the effects of absorber layer thickness and working temperature were investigated.

2. Numerical Modeling and Simulation

SCAPS was used to model and simulate the thin film solar cell. The basic idea behind this software is to use numerical differentiation and Gummel type iteration approach in order to resolve the continuous differential equations as well as Poisson's differential equation [11,12]. The purposed solar cell structure is "Back Contact/Perovskite/CdS/ZnO/Front Contact/Glass" here, where CH₃NH₃SnBr₃ Perovskites material is being used as an absorber layer, CdS as a buffer layer, and ZnO as a window layer. For the back and front contact, we used the SCAPS data by default. The value of absorption coefficient of each layer is taken from the SCAPS default value. All simulation settings for each layer in the structure are obtained from the literature [13–15].

3. Results and Discussion

Using SCAPS-1D simulator, simulation was carried out at 300 K working temperature under AM 1.5 G 1 sun illumination [16–18]. The effect of defects is not considered for this simulation and has been left for the researcher to check its effect. Energy band diagram taken from SCAPS-1D software is of proposed solar model "Back Contact/CH₃NH₃SnBr₃/CdS/ZnO/Front Contact" shown in Figure 1a. The energy bad diagram is used to discuss the optical properties of solar cell [19]. The band gap of CdS buffer layer is adjusted with CH₃NH₃SnBr₃ absorber and ZnO window layers. More or equal to 1.30 eV is the band gap level for incident light photons that is best for absorbing the majority of the light for maximum power conversion efficiency [20]. Here, in our case, the band gap of CH₃NH₃SnBr₃ absorber layer is 1.30 eV. Similarly, the band gaps of CdS and ZnO are 2.2 and 3.3 eV of these buffer and window layers, respectively.



Figure 1. Proposed Solar Cell's (**a**) Energy Band Diagram (**b**) J–V Curve under dark and sun (**c**) Initial J–V curve.

A photovoltaic cell's principal function is to convert light energy into electrical energy. A PV cell is a large flat diode that creates an exponential J–V curve in dark. A PV device produces a very low current value due to minority carriers in the dark. The solar cell starts to work when it is exposed to light, causing generation of charge carriers. Figure 1b is representing the J–V curve of our proposed solar cell under dark and suns both conditions. The simulation was run without any variation; an initial J–V curve that we plotted is represented in Figure 1c. We obtained an open circuit voltage (V_{oc}) of 0.797 V, and a short circuit current density (J_{sc}) of 35.5 mA/cm² was recorded. In the case of fill factor and efficiency, they were 68.24% and 19.34%, respectively. To observe the effect of thickness of perovskite absorber layer on the performance of the solar cell, the thickness was varied from 1.0 μ m to 3.0 μ m. By increasing the thickness from 1.0 μ m to 3.0 μ m, we observe that the J–V characteristics curve moves away from the origin as represented in Figure 2a. The effect of thickness on the P–V characteristics curves is also clear in Figure 2b. From this figure, we note that, by increasing the thickness of the absorber layer, the power density of a cell improves, because by increasing a thickness of absorber layer, the chance of photons capturing increases; hence, more sun power is converted into electrical power density. At 1.0 μ m thickness of CH₃NH₃SnBr₃, V_{oc} was 0.79 V, and J_{sc} was 35.2 mA/cm², and the fill factor of 57.45% and eta was recorded up to 16.17%, but when the thickness was increased from 1.0 μ m to 1.5 μ m, the characteristics parameters were changed to 0.795 V, 35.43 mA/cm², 63.79%, and 17.98%, respectively. Here, we observe that there is a major improvement in the efficiency, increasing by approximately 2% by increasing the thickness from 1.0 to 1.5 μ m.



Figure 2. (a) J–V characteristics curve (b) P–V characteristic curve affected by absorber layer thickness.

Working temperature has a significant impact on photovoltaic device performance. The photovoltaic panels were set up outside in the open. The performance of photovoltaic cells was reduced as a result of the increased heating in a solar cell due to sunshine. The temperature of solar cell panels was over 300 K. An impact of the proposed cell's operating temperature is also studied. We choose a temperature range of 290 to 330 K for our study. Figure 3a,b illustrate the simulation results of J–V and P–V characteristics curves affected by the working temperature.



Figure 3. (a) J–V and (b) P–V curves affected by the working temperature.

 V_{oc} is directly influenced by temperature, which has an impact on the overall performance of solar cells. As temperature rises, efficiency of solar cells decreases. Higher temperatures affect the material carrier concentration, band gaps, and electron and hole motilities, causing low efficiency [21].

Saturation current in reverse J_0 is temperature dependent, and as a result, V_{oc} drops as the temperature rises. As the temperature rises, the reverse saturation current decreases, and this drop in current is the primary source of the fall in V_{oc} , as seen in Equation (1) [22,23]. The greater working temperature provides more energy to electrons. Due to the increased temperature, these electrons are more likely to recombine with the holes before reaching the depletion area. The PCE of a cell diminishes as temperature rises; similarly, FF and V_{oc} both drop as the temperature rises; hence, the J_{sc} also decreases, as shown in Figure 4a,b.

$$J_e(V) = J_0 \left[exp\left(\frac{qV_{oc}}{k_B T}\right) - 1 \right]$$
⁽¹⁾



Here, in Table 1, we compare the results of the initial cell simulated with the optimized thickness and temperature operated purposed perovskite based solar cell.

Figure 4. Characteristics Parameters affected by the working temperature (**a**) *Eta* and *FF* vs. Temperature (**b**) V_{oc} and J_{sc} vs. Temperature.

Table 1. Comparison of characteristics parameters of purposed device at first and last optimized conations.

Simulation –	V _{oc} ,	J _{sc} ,	FF	Eta
	V	mA/cm ²	%	%
Initial	0.797	35.51	68.25	19.33
Optimized	0.813	35.58	73.17	21.16

We observed in Table 1 that, initially, the values of V_{oc} , J_{sc} , FF, and Eta were improved with optimized thickness and working temperature as shown in Table 1.

4. Conclusions

In this simulation study, we used a lead-free perovskite solar cell with model "Back Contact/CH₃NH₃SnBr₃/CdS/ZnO/Front Contact". We increased the thickness of buffer layer from 1.0 μ m to 3.0 μ m, and then efficiency increased from 16.17% to 20.81%. Here, we also observed the effect of temperature. The temperature was increased from 290 K to 330 K; hence, efficiency was reduced from 19.99% to 17.31%. Considering both the optimization parameters, CH₃NH₃SnBr₃ based perovskite solar cell exhibits the highest power conversion efficiency of 21.16% with the V_{oc} 0.813 V, J_{sc} 35.58 mA/cm², and FF 73.176%. The creation of an ecofriendly methyl ammonium tin bromide perovskite solar cell is shown by these results. This increment in efficiency is very remarkable and will be very helpful for the researchers and the scientist to develop the lead-free perovskite solar cell on an experimental scale.

Institutional Review Board Statement: The study did not involve humans or animals.

Informed Consent Statement: Not applicable.

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Conflicts of Interest: The authors declare that they have no conflicts of interest.

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